

AF(1762#

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Approved for use through 10/31/2002. OMB 0651-0031

U.S. Patent and Trademark Office: U.S. DEPARTMENT OF COMMERCE

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		Application Number		08/781,920			
TRANSMITTAL FORM			Filing Date		December 30, 1998		
(to be used for all correspondence after initial filing)			First Named Inventor		Takeshi FUKUNAGA et al.		
		Group Art Unit		1762			
			Examiner Name		M. PADGETT		
Total Number of Pages in This	Submission		Attorney Docket Number	r	740756-1614		
ENCLOSURES (check all that apply)							
			nent Papers		After Allowance Communication to Group		
Fee Attached		Drawing	Application)				
Amendment / Reply		Licensing-related Papers					
After Final		☐ Petition					
Affidavits/declaration(s)		Petition to Convert to a Provisional Application			,		
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☐ Information Disclosure Statement		☐ Termina	l Disclaimer				
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under 37 CFR 1.52 or 1.5	53				<b>、</b> ·		
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		Complete if Known		
FEE TRANSMITTAL		Application Number	08/781,920	
FOR FY 200		Filing Date	December 30, 1998	
FOR F 1 2001		First Named Inventor	Takeshi FUKUNAGA et al.	
		Examiner Name	M. PADGETT	
Patent fees are subject to annual revision.		Group Art Unit	1762	
TOTAL AMOUNT OF PAYMENT	(\$) 606.00	Attorney Docket No.	740756-1614	

METHOD OF PAYMENT	FEE CALCULATION (continued)			
1.   The Commissioner is hereby authorized to charge indicated	3. ADDITI	ONAL FEE	ES	
fees and credit any overpayments to:	Large Entity	-	,	
Deposit Account Number	Fee Fee Code (\$)	Fee Fee Code (\$)	Fee Description Fee Paid	
Number	105 130	205 65	Surcharge - late filing fee or oath	
Deposit Account Nixon Peabody LLP	127 50	227 25	Surcharge – late provisional filing fee or cover sheet	
Name	139 130	139 130	Non-English transaction	
Charge Any Additional Fee Required	147 2,520	147 2,520	For filing a request for ex parte reexamination	
Under 37 CFR 1.16 and 1.17	112 920*	112 920*	Requesting publication of SIR prior to Examiner	<del></del>
Applicant claims small entity status.  See 37 CFR 1.27	113 1,840*	1131,840*	action Requesting publication of SIR after Examiner action	
2. Z Payment Enclosed:	115 110	215 55	Extension for reply within first month	
•	116 390	216 195	Extension for reply within second month	390.00
Check Credit Card Money Other Order	117 890	217 445	Extension for reply within third month	370.00
FEE CALCULATION	118 1,390	218 695	Extension for reply within fourth month	
1. BASIC FILING FEE	128 1,890	228 945	Extension for reply within fifth month	<b>├</b>
Large Entity Small Entity	119 310	219 155	Notice of Appeal	
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101 710 201 355 Utility filing fee	121 270	221 135	Request for oral hearing Petition to institute a public use proceeding	
106 320 206 160 Design filing fee	138 1,510	138 1,510		THE I
107 490 207 245 Plant filing fee	140 110	240 55	Petition to revive – unavoidable	ф <u>;</u> [
108 710 208 355 Reissue filing fee	141 1,240	241 620	Petition to revive – unintentional	ら同
114 150 214 75 Provisional filing fee	142 1,240	242 620	Utility issue fee (or reissue)	
	143 440	243 220	Design issue fee	
SUBTOTAL (1) (\$) 0.00	144 600	244 300	Petition to revive – unavoidable  Petition to revive – unintentional  Utility issue fee (or reissue)  Design issue fee  Plant issue fee	
2, EXTRA CLAIM FEES	122 130	122 130	Petitions to the Commissioner	
Fee from	123 50	123 50	Petitions related to provisional applications	
Total Claims $52$ $-40^{**} = \begin{bmatrix} Extra Claims & below & Fee Paid \\ -0 & X & 12 & = 216.00 \end{bmatrix}$	126 180	126 180	Submission of Information Disclosure Stmt	
Independent 9 -14** = -0- X = -0-	581 40	581 40	Recording each patent assignment per property (times number of properties)	
Multiple Dependent =	146 710	246 355	Filing a submission after final rejection (37 CFR § 1.129(a))	
Large Entity Small Entity Fee Fee Fee Fee Description	149 710	249 355	For each additional invention to be examined (37 CFR § 1.29(b))	
Code (\$) Code (\$)	179 710	249 355	Request for Continued Examination (RCE)	
103 18 203 9 Claims in excess of 20	169 900	169 900	Request for expedited examination of a design application	
102 80 202 40 Independent claims in excess of 3	Other fee (spec	cify)	FICATE OF MAILING	
104 270 204 135 Multiple dependent claim, if not paid	l			
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SUBTOTAL (2) (\$) 216.00	20231, @	n 5/	LOLLEN INNET	7-11
**or number previously paid, if greater; For Reissues, see above			- June 1	
SUBMITTED BY			Complete (if applicable)	
Donald R. Studehaker	Registration		0.15	9110
Name (Print/Type)	(Attorney/Ag	gent)	Z,815 Telephone 703/790-	

Signature May 7, 2001

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Expedited Procedure **Examining Group 1762** 

Docket No: 740756-161

## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of	)	
Takeshi FUKUNAGA et al	)	
Serial No.: 08/781,920 V	) Group Art Unit: 1762	
Filed: December 30, 1998	) Examiner: M. PADGETT	
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,	Wendy K. Spradlin	_

## **AMENDMENT**

Commissioner for Patents Washington, D. C. 20231

Sir:

Responsive to the Office Action of December 6, 2000, the period for response having been extended two (2) months until May 6, 2001 (Sunday), the following amendments and remarks are respectfully submitted in connection with the above-identified application.

## **IN THE SPECIFICATION:**

On page 33, replace the second full paragraph with the following:

Thereafter, the substrate is subjected to annealing by laser light irradiation. Although a KrF excimer laser (wavelength: 248 nm; pulse width: 20 nsec) is used in this embodiment, other lasers may also be used. As for the laser light irradiation conditions, the energy density is 200 to 400 mJ/cm<sup>2</sup>, for instance, 250 mJ/ cm<sup>2</sup>, and 2 to 10 shots, for instance, 2 shots, are applied per one location. The annealing effect may be enhanced by heating the substrate to 200 to 450° during the RECEIVED

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C 1700 MAIL ROO! irradiation (Fig. 5(C)).

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